

## VS-VSKL300/08PbF

Vishay Semiconductors

# INT-A-PAK Power Module Thyristor/Diode, 300 A



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INT-A-PAK

PRIMARY CHARACTERISTICS				
I <sub>T(AV)</sub>	300 A			
Type	Modules -thyristor, standard			
Package	INT-A-PAK			

#### **FEATURES**

- · Electrically isolated base plate
- 3000 V<sub>RMS</sub> isolating voltage
- Industrial standard package
- Simplified mechanical designs, rapid assembly
- High surge capability
- Large creepage distances
- UL approved file E78996
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **APPLICATIONS**

- · Battery chargers
- Welders
- Power converters
- Alternators

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
V <sub>DRM</sub> /V <sub>RRM</sub>		800	V				
I <sub>T(AV)</sub>	53 °C	300	Α				
I <sub>T(RMS)</sub>		116	Α				
	50 Hz	6500	A				
I <sub>TSM</sub>	60 Hz	6900	A				
I <sup>2</sup> t	50 Hz	214	kA <sup>2</sup> s				
1-1	60 Hz	195	KA-S				
l <sup>2</sup> √t		2140	kA <sup>2</sup> √s				
T <sub>J</sub>	Range	-40 to +140	°C				

#### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS								
TYPE NUMBER	V <sub>RRM</sub> /V <sub>DRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> /V <sub>DSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> /I <sub>DRM</sub> AT 125 °C mA					
VS-VSKL300/08PbF	800	900	50					

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ON-STATE CONDUCTION PARAMETER	SYMBOL		TEST CONDITION	ONS	VALUES	UNITS	
Maximum average on-state current	01202					A	
at case temperature	$I_{T(AV)}$	180° conducti	on half sine wave		300 53	°C	
Maximum RMS on-state current	I <sub>T(RMS)</sub>	As AC switch			116		
	,	t = 10 ms	No voltage		6600		
Maximum peak, one-cycle		t = 8.3 ms	reapplied		6900	Α	
on-state, non-repetitive surge current	I <sub>TSM</sub>	t = 10 ms	100 % V <sub>RRM</sub>		5500	1	
3		t = 8.3 ms	reapplied	Sine half wave, 5	5800		
		t = 10 ms	No voltage	initial $T_J = T_J$ maximum	214	- kA <sup>2</sup> s	
Maximum I <sup>2</sup> t for fusing	I <sup>2</sup> t	t = 8.3 ms	reapplied		195		
	1-1	t = 10 ms	100 % V <sub>BBM</sub>		151		
		t = 8.3 ms	reapplied		138		
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t	t = 0.1 ms to 1	t = 0.1 ms to 10 ms, no voltage reapplied			kA²√s	
Low level value of threshold voltage	V <sub>T(TO)1</sub>	(16.7 % x π x	$I_{T(AV)} < I < \pi \times I_{T(AV)},$	T <sub>J</sub> maximum	0.796	V	
High level value of threshold voltage	V <sub>T(TO)2</sub>	$(I > \pi \times I_{T(AV)}),$	$(I > \pi \times I_{T(AV)})$ , $T_J$ maximum			]	
Low level value on-state slope resistance	r <sub>t1</sub>	(16.7 % x $\pi$ x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$ ), $T_J$ maximum			0.972	0	
High level value on-state slope resistance	r <sub>t2</sub>	$(I > \pi \times I_{T(AV)})$ , $T_J$ maximum			0.88	mΩ	
Maximum on atata valtaga deen	$V_{TM}$	T 05 %C 1	500 A	SCR	1.35		
Maximum on-state voltage drop	V <sub>EM</sub>	$T_J = 25  ^{\circ}\text{C},  I_{pk} = 500  \text{A}$		DIODE	1.20	V	

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Typical delay time	t <sub>d</sub>	Gate current 1 A, $dl_g/dt = 1 A/\mu s$ $V_d = 0.67 \% V_{DRM}$ , $T_J = 25 °C$	1.0	
Typical turn-off time	t <sub>q</sub>	$I_{TM}$ = 300 A, $T_J$ = $T_J$ maximum, dl/dt = 20 A/μs, $V_R$ = 50 V dV/dt = 20 V/μs, Gate 0 V 100 $\Omega$ , $t_p$ = 500 μs	100	μs

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum linear to 67 % rated $V_{DRM}$	500	V/µs
Maximum peak reverse and off-state leakage current	I <sub>DRM</sub> , I <sub>RRM</sub>	$T_J = T_J$ maximum, rated $V_{DRM}/V_{RRM}$ applied	50	mA
RMS insulation voltage	V <sub>INS</sub>	50 Hz, circuit to base, all terminal shorted, t = 1 s	3000	V



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TRIGGERING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum peak gate power	P <sub>GM</sub>	$T_J = T_J$ maximum, $t_p \le 5$ ms	10.0	W	
Maximum average gate power	P <sub>G(AV)</sub>	$T_J = T_J$ maximum, $f = 50$ Hz, $d\% = 50$	2.0	] vv	
Maximum peak positive gate current	I <sub>GM</sub>	$T_J = T_J$ maximum, $t_p \le 5$ ms	3.0	Α	
Maximum required DC gate voltage to trigger	$V_{GT}$	T 05.00	3	V	
Maximum required DC gate current to trigger	I <sub>GT</sub>	$T_J = 25 ^{\circ}\text{C}$ Anode supply: 12 V resistive load	200	mA	
Maximum holding current	I <sub>H</sub>	7 Trodo cappiy. 12 v Toolotivo load	600	IIIA	
Maximum peak positive gate voltage	+V <sub>GM</sub>	T <sub>J</sub> = T <sub>J</sub> maximum, t <sub>p</sub> ≤ 5 ms	20	V	
Maximum peak negative gate voltage	-V <sub>GM</sub>	$ij = ij \text{ maximum}, i_p \le 3 \text{ ms}$	5.0	V	
DC gate voltage not to trigger	$V_{GD}$	$T_J = T_J$ maximum	0.30	V	
DC gate current not to trigger	I <sub>GD</sub>	Maximum gate current/voltage not to trigger is the maximum value which will not trigger any unit with rated V <sub>DRM</sub> anode to cathode applied	10	mA	
Maximum non-repetitive rate of rise of turned-on current	dl/dt	Gate drive 20 V, 20 $\Omega$ , $t_r \le 1~\mu s$ $T_J = T_J$ maximum, anode voltage $\le 80~\%$ $V_{DRM}$	1000	A/µs	

THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction operating temperature range	TJ		-40 to +140	°C			
Maximum storage temperature range	T <sub>Stg</sub>		-40 to +150				
Maximum thermal resistance, junction to case per junction	R <sub>thJC</sub>	DC operation	0.19	K/W			
Maximum thermal resistance, case to heatsink per module	R <sub>thCS</sub>	Mounting surface smooth, flat and greased	0.035	N/VV			
Mounting torque + 10 %	k	A mounting compound is recommended and	4 to 6	Nima			
Mounting torque ± 10 % busbar to IAF	•	the torque should be rechecked after a period	4 10 6	Nm			
Approximate weight		of 3 hours to allow for the spread of the	500	g			
Approximate weight		compound. Lubricated threads.	17.8	OZ.			
Case style			INT-A-F	AK			

△R CONDUCTION PER JUNCTION											
DEVICES		SINUSOIDAL CONDUCTION AT T <sub>J</sub> MAXIMUM			RECTANGULAR CONDUCTION AT T <sub>J</sub> MAXIMUM				UNITS		
	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	
VSKL300	0.019	0.022	0.028	0.041	0.068	0.013	0.023	0.031	0.043	0.069	K/W

#### Note

Table shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC

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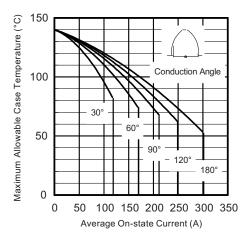


Fig. 1 - Current Ratings Characteristics

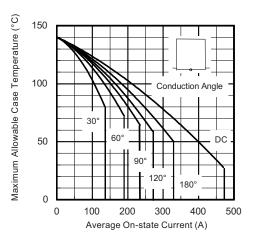


Fig. 2 - Current Ratings Characteristics

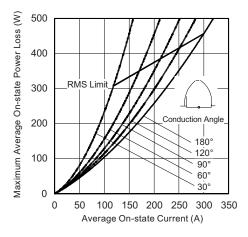


Fig. 3 - On-State Power Loss Characteristics

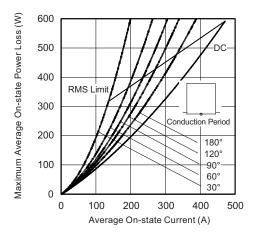


Fig. 4 - On-State Power Loss Characteristics

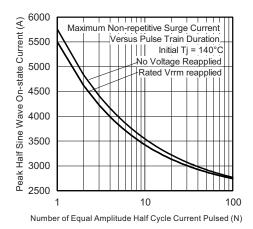


Fig. 5 - Maximum Non-Repetitive Surge Current

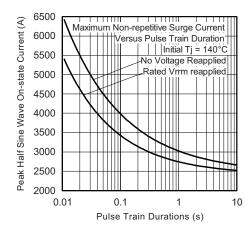


Fig. 6 - Maximum Non-Repetitive Surge Current

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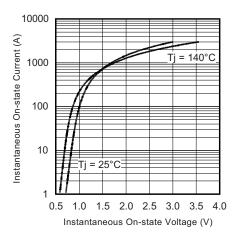


Fig. 7 - On-State Voltage Drop Characteristics (SCR)

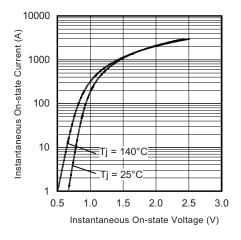


Fig. 8 - On-State Voltage Drop Characteristics (Diode)

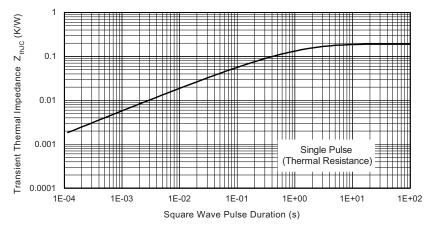
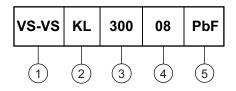


Fig. 9 - Thermal Impedance Z<sub>thJC</sub> Characteristics

#### **ORDERING INFORMATION TABLE**

Device code



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2 - Circuit configuration

Current rating (300 = 300 A)

Voltage rating (08 = 800 V)

5 - PbF = Lead (Pb)-free

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CIRCUIT CONFIGURATION						
CIRCUIT DESCRIPTION	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING				
SCR/diode doubler circuit, negative control	L	1 0 ~ 2 0+ 1 0 ~ 2 0+ 1 0 ~ 1 0				

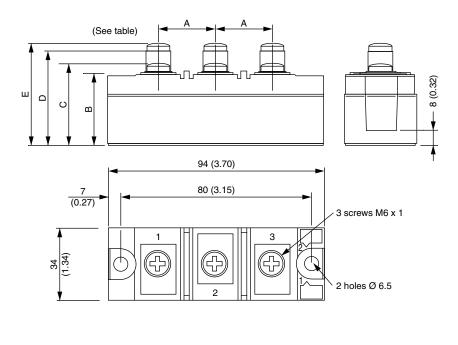
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95010			



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# **INT-A-PAK Diode**

#### **DIMENSIONS** in millimeters (inches)



Α	В	С	D	E
23 (0.91)	30 (1.18)	36 (1.42)	-	-



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